5V ECL Triple Differential 2:1 Multiplexer

The MC10E457/100E457 is a 3-bit differential 2:1 multiplexer. The fully differential data path makes the device ideal for multiplexing low skew clock or other skew sensitive signals.

The higher frequency outputs provide the device with a > 1.0 GHz bandwidth to meet the needs of the most demanding system clock.

Both, separate selects and a common select, are provided to make the device well suited for both data path and random logic applications.

The differential inputs have internal clamp structures which will force the Q output of a gate in an open input condition to go to a LOW state. Thus, inputs of unused gates can be left open and will not affect the operation of the rest of the device. Note that the input clamp will take affect only if both inputs fall 2.5 V below VCC.

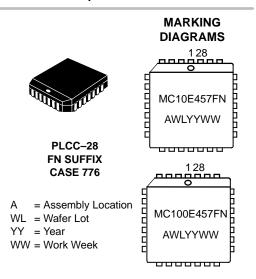
The 100 Series contains temperature compensation.

Multiple V_{BB} pins are provided to ease AC coupling input signals. The V_{BB} pins, internally generated voltage supply pins, are available to this device only. For single-ended input conditions, the unused differential input is connected to V_{BB} as a switching reference voltage. V_{BB} may also rebias AC coupled inputs. When used, decouple V_{BB} and V_{CC} via a 0.01 μF capacitor and limit current sourcing or sinking to 0.5 mA. When not used, V_{BB} should be left open.

- Differential D and Q; VBB available
- 700 ps Max. Propagation Delay
- High Frequency Outputs
- Separate and Common Select
- PECL Mode Operating Range: V_{CC} = 4.2 V to 5.7 V with V_{EE} = 0 V
- NECL Mode Operating Range: V_{CC} = 0 V with V_{EE} = -4.2 V to -5.7 V
- Internal Input Pulldown Resistors
- ESD Protection: > 2 KV HBM, > 200 V MM
- Meets or Exceeds JEDEC Spec EIA/JESD78 IC Latchup Test
- Moisture Sensitivity Level 1
 For Additional Information, see Application Note AND8003/D
- Flammability Rating: UL-94 code V-0 @ 1/8", Oxygen Index 28 to 34
- Transistor Count = 218 devices

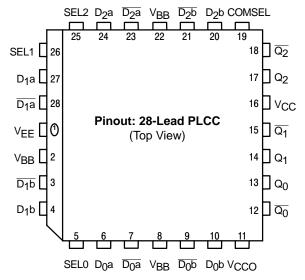


http://onsemi.com



ORDERING INFORMATION

Device	Package	Shipping				
MC10E457FN	PLCC-28	37 Units/Rail				
MC10E457FNR2	PLCC-28	500 Units/Reel				
MC100E457FN	PLCC-28	37 Units/Rail				
MC100E457FNR2	PLCC-28	500 Units/Reel				



^{*} All V_{CC} and V_{CCO} pins are tied together on the die.

Warning: All V_{CC}, V_{CCO}, and V_{EE} pins must be externally connected to Power Supply to guarantee proper operation.

Figure 1. Pinout Assignment

PIN DESCRIPTION

PIN	FUNCTION
Dn[0:2]; Dn [0:2]	ECL Differential Data Inputs
SEL	ECL Individual Select Input
COMSEL	ECL Common Select Input
Q[0:2], Q[0:2]	ECL Differential Data Outputs
V _{BB}	Reference Voltage Output
Vcc, Vcco	Positive Supply
VEE	Negative Supply

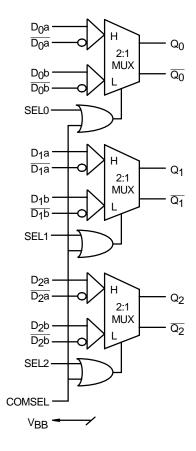


Figure 2. Logic Diagram

FUNCTION TABLE

SEL	Data
Н	а
L	b

MAXIMUM RATINGS (Note 1)

Symbol	Parameter	Condition 1	Condition 2	Rating	Units
Vcc	PECL Mode Power Supply	VEE = 0 V		8	V
VEE	NECL Mode Power Supply	VCC = 0 V		-8	V
VI	PECL Mode Input Voltage NECL Mode Input Voltage	V _{EE} = 0 V	$V_I \leq V_{CC}$ $V_I \geq V_{EE}$	6 -6	V V
l _{out}	Output Current	Continuous Surge		50 100	mA mA
I _{BB}	V _{BB} Sink/Source			± 0.5	mA
TA	Operating Temperature Range			0 to +85	°C
T _{stg}	Storage Temperature Range			-65 to +150	°C
θJA	Thermal Resistance (Junction-to-Ambient)	0 LFPM 500 LFPM	28 PLCC 28 PLCC	63.5 43.5	°C/W
θЈС	Thermal Resistance (Junction-to-Case)	std bd	28 PLCC	22 to 26	°C/W
VEE	PECL Operating Range NECL Operating Range			4.2 to 5.7 -5.7 to -4.2	V V
T _{sol}	Wave Solder	< 2 to 3 sec @ 248°C		265	°C

^{1.} Maximum Ratings are those values beyond which device damage may occur.

10E SERIES PECL DC CHARACTERISTICS $V_{CCx} = 5.0 \text{ V}$; $V_{EE} = 0.0 \text{ V}$ (Note 2)

			–40°C			0°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current		92	110		92	110		92	110		92	110	mA
Vон	Output HIGH Voltage (Note 3)				3980	4070	4160	4020	4105	4190	4090	4185	4280	mV
V _{OL}	Output LOW Voltage (Note 3)				3050	3210	3370	3050	3210	3370	3050	3227	3405	mV
V _{IH}	Input HIGH Voltage (Single–Ended)				3830	3995	4160	3870	4030	4190	3940	4110	4280	mV
V _{IL}	Input LOW Voltage (Single–Ended)				3050	3285	3520	3050	3285	3520	3050	3302	3555	mV
V _{BB}	Output Voltage Reference	3.57		3.7	3.62		3.73	3.65		3.75	3.69		3.81	V
VIHCMR	Input HIGH Voltage Common Mode Range (Differential) (Note 4)				2.7		5.0	2.7		5.0	2.7		5.0	V
lΗ	Input HIGH Current			150			150			150			150	μΑ
I _{IL}	Input LOW Current				0.5	0.3		0.5	0.25		0.3	0.2		μΑ

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.

- 2. Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary +0.46 V / -0.06 V.
 3. Outputs are terminated through a 50 Ω resistor to V_{CC}-2 volts.
 4. V_{IHCMR} min varies 1:1 with V_{EE}, max varies 1:1 with V_{CC}.

10E SERIES NECL DC CHARACTERISTICS $V_{CCx} = 0.0 \text{ V}$; $V_{EE} = -5.0 \text{ V}$ (Note 5)

			–40°C		0°C 25°C									
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
IEE	Power Supply Current		92	110		92	110		92	110		92	110	mA
VOH	Output HIGH Voltage (Note 6)				-1020	-930	-840	-980	-895	-810	-910	-815	-720	mV
VOL	Output LOW Voltage (Note 6)				-1950	-1790	-1630	-1950	-1790	-1630	-1950	-1773	-1595	mV
VIH	Input HIGH Voltage (Single–Ended)				-1170	-1005	-840	-1130	-970	-810	-1060	-890	-720	mV
V _{IL}	Input LOW Voltage (Single–Ended)				-1950	-1715	-1480	-1950	-1715	-1480	-1950	-1698	-1445	mV
V _{BB}	Output Voltage Reference	-1.43		-1.3	-1.38		-1.27	-1.35		-1.25	-1.31		-1.19	V
VIHCMR	Input HIGH Voltage Common Mode Range (Differential) (Note 7)				-2.3		0.0	-2.3		0.0	-2.3		0.0	V
I _{IH}	Input HIGH Current			150			150			150			150	μΑ
IIL	Input LOW Current				0.5	0.3		0.5	0.065		0.3	0.2		μΑ

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.

- 5. Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary +0.46 V / -0.06 V. 6. Outputs are terminated through a 50 Ω resistor to V_{CC}-2 volts. 7. V_{IHCMR} min varies 1:1 with V_{EE}, max varies 1:1 with V_{CC}.

100E SERIES PECL DC CHARACTERISTICS $V_{CCx} = 5.0 \text{ V}$; $V_{EE} = 0.0 \text{ V}$ (Note 8)

			–40°C			0°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current		92	110		92	110		92	110		106	127	mA
Vон	Output HIGH Voltage (Note 9)				3975	4050	4120	3975	4050	4120	3975	4050	4120	mV
V _{OL}	Output LOW Voltage (Note 9)				3190	3295	3380	3190	3255	3380	3190	3260	3380	mV
V _{IH}	Input HIGH Voltage (Single–Ended)				3835	4050	4120	3835	4120	4120	3835	4120	4120	mV
V _{IL}	Input LOW Voltage (Single–Ended)				3190	3300	3525	3190	3525	3525	3190	3525	3525	mV
V _{BB}	Output Voltage Reference	3.62		3.74	3.62		3.74	3.62		3.74	3.62		3.74	V
VIHCMR	Input HIGH Voltage Common Mode Range (Differential) (Note 10)				2.7		5.0	2.7		5.0	2.7		5.0	V
lН	Input HIGH Current			150			150			150			150	μΑ
I _{IL}	Input LOW Current				0.5	0.3		0.5	0.25		0.5	0.2		μΑ

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.

8. Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary +0.46 V / -0.8 V.

9. Outputs are terminated through a 50 Ω resistor to V_{CC}-2 volts.

10. V_{IHCMR} min varies 1:1 with V_{EE}, max varies 1:1 with V_{CC}.

100E SERIES NECL DC CHARACTERISTICS $V_{CCx} = 0.0 \text{ V}$; $V_{EE} = -5.0 \text{ V}$ (Note 11)

			–40°C			0°C		25°C				85°C		
Symbol	Characteristic	Min	Тур	Max	Unit									
IEE	Power Supply Current		92	110		92	110		92	110		106	127	mA
Vон	Output HIGH Voltage (Note 12)				-1025	-950	-880	-1025	-950	-880	-1025	-950	-880	mV
VOL	Output LOW Voltage (Note 12)				-1810	-1705	-1620	-1810	-1745	-1620	-1810	-1740	-1620	mV
VIH	Input HIGH Voltage (Single–Ended)				-1165	-950	-880	-1165	-880	-880	-1165	-880	-880	mV
V _{IL}	Input LOW Voltage (Single–Ended)				-1810	-1700	-1475	-1810	-1475	-1475	-1810	-1475	-1475	mV
V _{BB}	Output Voltage Reference	-1.38		-1.26	-1.38		-1.26	-1.38		-1.26	-1.38		-1.26	V
VIHCMR	Input HIGH Voltage Common Mode Range (Differential) (Note 13)				-2.3		0.0	-2.3		0.0	-2.3		0.0	V
I _{IH}	Input HIGH Current			150			150			150			150	μΑ
I _{IL}	Input LOW Current				0.5	0.3		0.5	0.25		0.5	0.2		μΑ

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.

- 11. Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary +0.46 V / -0.8 V. 12. Outputs are terminated through a 50 Ω resistor to V_{CC}-2 volts. 13. V_{IHCMR} min varies 1:1 with V_{EE}, max varies 1:1 with V_{CC}.

AC CHARACTERISTICS $V_{CCx} = 5.0 \text{ V}; V_{EE} = 0.0 \text{ V} \text{ or } V_{CCx} = 0.0 \text{ V}; V_{EE} = -5.0 \text{ V} \text{ (Note 14)}$

			0°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
fMAX	Maximum Toggle Frequency		TBD			TBD			TBD		GHz
^t PLH ^t PHL	Propagation Delay to Output D (Differential) D (Single-Ended) SEL COMSEL	325 275 300 325	475 475 500 525	700 750 775 800				375 325 350 375	475 475 500 525	650 700 725 750	ps
^t skew	Within-Device Skew (Note 15)		40						40		ps
tskew	Duty Cycle Skew (Note 16) tpLH - tpHL		±10						±10		ps
^t JITTER	Cycle-to-Cycle Jitter		TBD			TBD			TBD		ps
V_{PP}	Input Voltage Swing (Differential) (Note 17)	150						150			mV
t _r /t _f	Rise/Fall Time 20-80%	125	275	500				150	275	450	ps

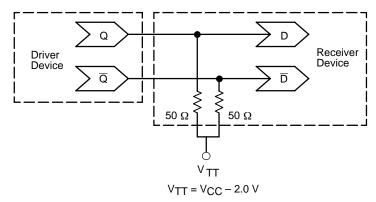
^{14.10} Series: VEE can vary +0.46 V / -0.06 V.

100 Series: VEE can vary +0.46 V / -0.8 V.

15. Within-device skew is defined as identical transitions on similar paths through a device.

16. Duty cycle skew is defined only for differential operation when the delays are measured from the cross point of the inputs to the cross point of the outputs.

^{17.} Minimum input swing for which AC parameters are guaranteed.



Typical Termination for Output Driver and Device Evaluation (See Application Note AND8020 – Termination of ECL Logic Devices.)

Resource Reference of Application Notes

AN1404 – ECLinPS Circuit Performance at Non–Standard VIH Levels

AN1405 – ECL Clock Distribution Techniques

AN1406 – Designing with PECL (ECL at +5.0 V)

AN1503 - ECLinPS I/O SPICE Modeling Kit

AN1504 — Metastability and the ECLinPS Family

AN1568 – Interfacing Between LVDS and ECL

AN1596 - ECLinPS Lite Translator ELT Family SPICE I/O Model Kit

AN1650 – Using Wire-OR Ties in ECLinPS Designs

AN1672 – The ECL Translator Guide

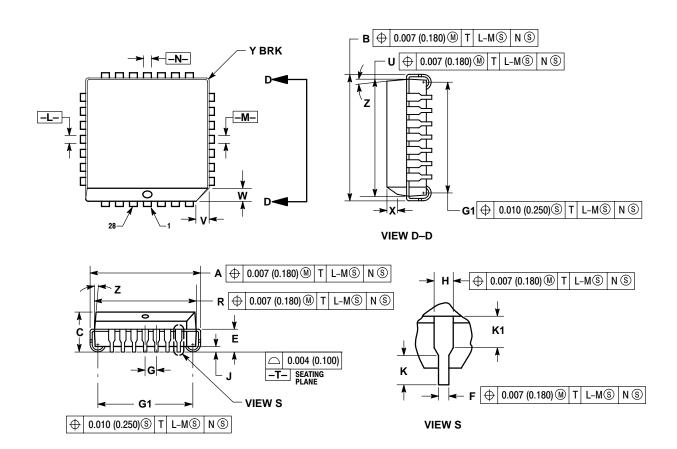
AND8001 – Odd Number Counters Design

AND8002 - Marking and Date Codes

AND8020 – Termination of ECL Logic Devices

PACKAGE DIMENSIONS

PLCC-28 **FN SUFFIX** PLASTIC PLCC PACKAGE CASE 776-02 **ISSUE E**



- OTES:

 NOTE:

 NO
- MOLD FLASH. ALLOWABLE MOLD FLASH IS 0.010 (0.250) PER SIDE.
- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- ANSI Y14.5M, 1982.
 5. CONTROLLING DIMENSION: INCH.
 6. THE PACKAGE TOP MAY BE SMALLER THAN THE PACKAGE BOTTOM BY UP TO 0.012 (0.300). DIMENSIONS R AND U ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, GATE BURRS AND INTERLEAD FLASH, BUT INCLUDING ANY MISMATCH BETWERN THE TOP AND ROTTOM OF THE BETWEEN THE TOP AND BOTTOM OF THE PLASTIC BODY.
- 7. DIMENSION H DOES NOT INCLUDE DAMBAR PROTRUSION OR INTRUSION. THE DAMBAR PROTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE GREATER THAN 0.037 (0.940). THE DAMBAR INTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE SMALLER THAN 0.025 (0.635).

	INC	HES	MILLIM	ETERS
DIM	MIN	MAX	MIN	MAX
Α	0.485	0.495	12.32	12.57
В	0.485	0.495	12.32	12.57
C	0.165	0.180	4.20	4.57
Е	0.090	0.110	2.29	2.79
F	0.013	0.019	0.33	0.48
G	0.050	BSC	1.27	BSC
Н	0.026	0.032	0.66	0.81
J	0.020		0.51	
K	0.025		0.64	
R	0.450	0.456	11.43	11.58
U	0.450	0.456	11.43	11.58
٧	0.042	0.048	1.07	1.21
W	0.042	0.048	1.07	1.21
Х	0.042	0.056	1.07	1.42
Υ		0.020	-	0.50
Z	2 °	10°	2°	10°
G1	0.410	0.430	10.42	10.92
K1	0.040		1.02	

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